



### **NPN General Purpose Switching Transistor**

Voltage

40V

Current

600mA

#### **Features**

- NPN epitaxial Silicon, Planar Design
- Collector-emitter voltage VCE = 40V
- Collector current = 600mA
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

#### **Mechanical Data**

• Case: SOT-89 Package

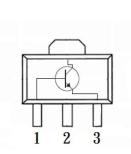
• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.002 ounces, 0.057grams

Marking: C2H

#### **SOT-89**





Pin Assignment: 1. Base

2. Collector

3. Emitter

# **Maximum Ratings and Thermal Characteristics** ( $T_A$ =25 $^{\circ}$ C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Collector-Base Voltage	$V_{CBO}$	75	V
Collector-Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current (DC)	Ic	600	mA
Collector Current (Pulse)	I <sub>CP</sub>	800	mA
Total Power Dissipation	Ртот	1.1	W
Junction to Ambient (Note1)	$R_{\theta JA}$	250	°C/W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55~150	°C

Note1: Transistor mounted on a FR4 PCB, single-sided copper, tin-plated and standard footprint.





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
OFF Characteristics						
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1.0mA, I <sub>B</sub> = 0A	40	-	-	V
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	$I_C=10uA$ , $I_E=0A$	75	-	-	V
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 10uA, I <sub>C</sub> = 0A	6	-	-	V
Collector-Base Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> = 60V, I <sub>E</sub> = 0A	-	-	10	nA
Emitter-Base Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> = 3V	-	-	10	nA
Collector-Emitter Cutoff Current	I <sub>CES</sub>	V <sub>CES</sub> = 60V	ı	-	10	nA
ON characteristics						
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> = 10V I <sub>C</sub> = 0.1mA	35	-	-	- - - -
		V <sub>CE</sub> = 10V I <sub>C</sub> = 1mA	50	-	-	
		V <sub>CE</sub> = 10V I <sub>C</sub> = 10mA	75	-	-	
		V <sub>CE</sub> = 10V I <sub>C</sub> = 150mA	100	-	300	
		V <sub>CE</sub> = 1V I <sub>C</sub> = 150mA	50	-	-	
		V <sub>CE</sub> = 10V I <sub>C</sub> = 500mA	40	-	-	
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA	-	-	0.3	V
		I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	-	-	1.0	
Base-Emitter Saturation voltage	V <sub>BE(SAT)</sub>	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA	-	-	1.2	V
		I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	-	-	2.0	
Collector-Base Capacitance	C <sub>CBO</sub>	V <sub>CB</sub> = 10V, f=1MHz	-	-	8	
Emitter-Base Capacitance	C <sub>EBO</sub>	V <sub>CB</sub> = 0.5V, f=1MHz	-	-	25	pF
Delay Time	td	VCC= 3V, VBE= -5V	-	-	10	
Rise Time	tr	IC= 150mA, IB= 15mA	-	-	25	nS
Storage Time	ts	VCC= 30V, IC= 150mA	-	-	225	
Fall Time	tf	IB1 = IB2 = 15mA	-	-	60	
Turn-on Time	ton	IC= 150mA,Ibon =15mA	-	-	35	
Turn-off Time	toff	Iboff = -15mA	-	-	250	
Transition Frequency	fT	VCE = 10 V; IC = 20mA F = 100 MHz	300	-	-	MHz





#### **TYPICAL CHARACTERISTIC CURVES**

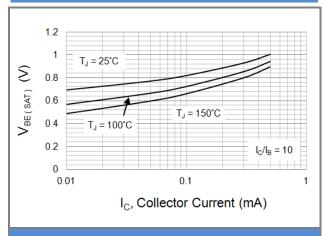


Fig.1 Typical Base-Emitter Saturation Voltage

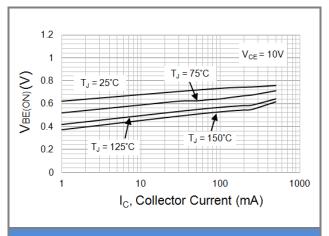


Fig.2 Typical Base-Emitter Turn-on Voltage

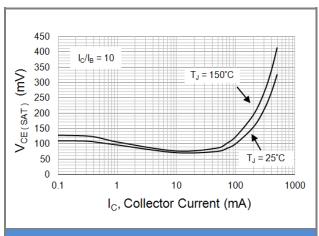
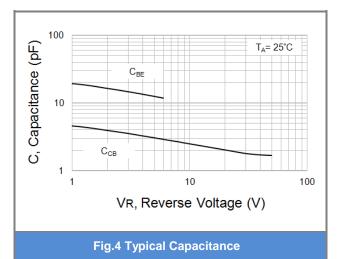
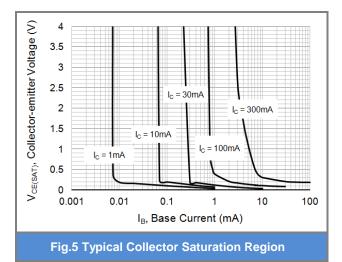


Fig.3 Typical Collector-Emitter Saturation





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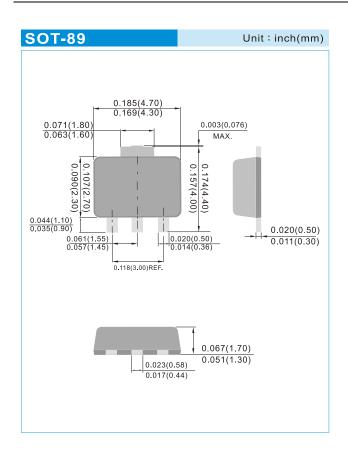


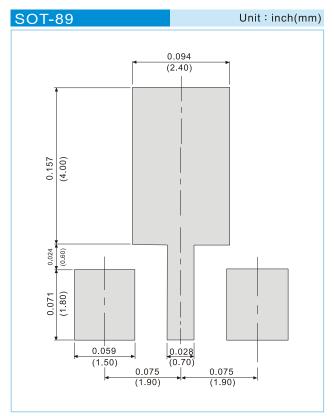


#### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
2SC2222H_R1_00001	SOT-89	1000pcs / 7" reel	C2H	Halogen free

#### **Packaging Information & Mounting Pad Layout**





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